

勝特力材料 886-3-5753170  
 勝特力电子(上海) 86-21-34970699  
 勝特力电子(深圳) 86-755-83298787  
 Http://www.100y.com.tw

**FAIRCHILD**  
 SEMICONDUCTOR™

## BDX54/A/B/C

**Hammer Drivers, Audio Amplifiers Applications  
 Power Liner and Switching Applications**

- Power Darlington TR
- Complement to BDX53, BDX53A, BDX53B and BDX53C respectively



TO-220  
 1.Base 2.Collector 3.Emitter

### PNP Epitaxial Silicon Transistor

**Absolute Maximum Ratings**  $T_C=25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage : BDX54	- 45	V
	: BDX54A	- 60	V
	: BDX54B	- 80	V
	: BDX54C	- 100	V
$V_{CEO}$	Collector-Emitter Voltage : BDX54	- 45	V
	: BDX54A	- 60	V
	: BDX54B	- 80	V
	: BDX54C	- 100	V
$V_{EBO}$	Emitter-Base Voltage	- 5	V
$I_C$	Collector Current (DC)	- 8	A
$I_{CP}$	*Collector Current (Pulse)	- 12	A
$I_B$	Base Current	- 0.2	A
$P_C$	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	60	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

**Electrical Characteristics**  $T_C=25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	* Collector-Emitter Sustaining Voltage : BDX54	$I_C = - 100\text{mA}, I_B = 0$	- 45			V
	: BDX54A					
	: BDX54B					
	: BDX54C					
$I_{CBO}$	Collector Cut-off Current : BDX54	$V_{CB} = - 45\text{V}, I_E = 0$			- 200	$\mu\text{A}$
	: BDX54A	$V_{CB} = - 60\text{V}, I_E = 0$			- 200	$\mu\text{A}$
	: BDX54B	$V_{CB} = - 80\text{V}, I_E = 0$			- 200	$\mu\text{A}$
	: BDX54C	$V_{CB} = - 100\text{V}, I_E = 0$			- 200	$\mu\text{A}$
$I_{CEO}$	Collector Cut-off Current : BDX54	$V_{CE} = - 22\text{V}, I_B = 0$			- 500	$\mu\text{A}$
	: BDX54A	$V_{CE} = - 30\text{V}, I_B = 0$			- 500	$\mu\text{A}$
	: BDX54B	$V_{CE} = - 40\text{V}, I_B = 0$			- 500	$\mu\text{A}$
	: BDX54C	$V_{CE} = - 50\text{V}, I_B = 0$			- 500	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = - 5\text{V}, I_C = 0$			- 2	mA
$h_{FE}$	* DC Current Gain	$V_{CE} = - 3\text{V}, I_C = - 3\text{A}$	750			
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = - 3\text{A}, I_B = - 12\text{mA}$			- 2	V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = - 3\text{A}, I_B = - 12\text{mA}$			- 2.5	V
$V_F$	* Parallel Diode Forward Voltage	$I_F = - 3\text{A}$		- 1.8	- 2.5	V
		$I_F = - 8\text{A}$		- 2.5		V

\* Pulse Test: PW=300 $\mu\text{s}$ , duty Cycle =1.5% Pulsed

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## Typical Characteristics

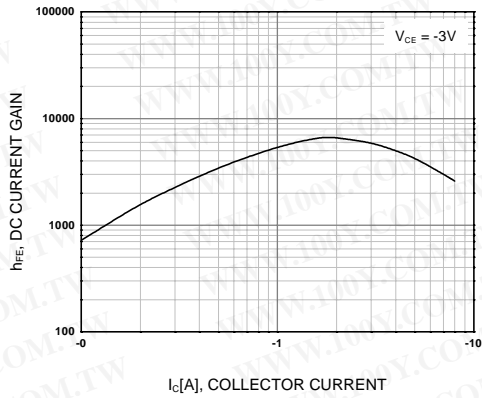


Figure 1. DC current Gain

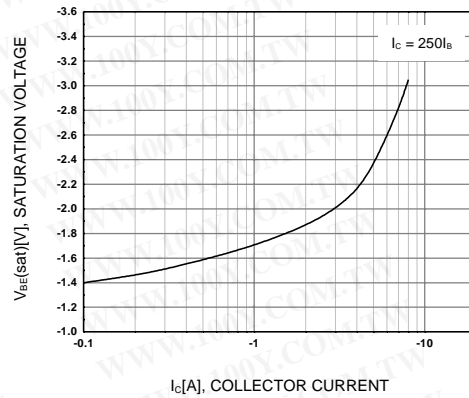


Figure 2. Base-Emitter Saturation Voltage

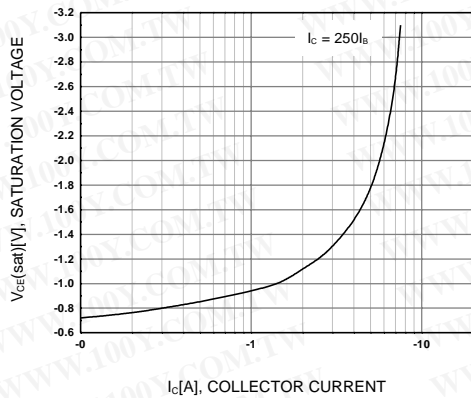


Figure 3. Collector-Emitter Saturation Voltage

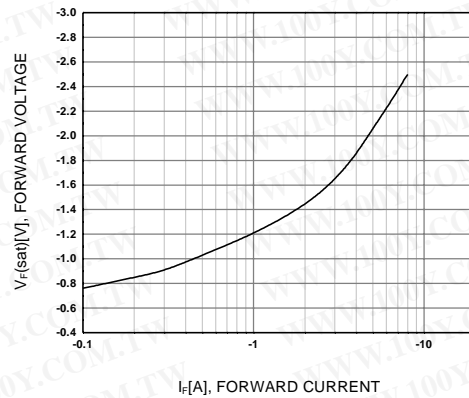


Figure 4. Damper Diode Forward Voltage

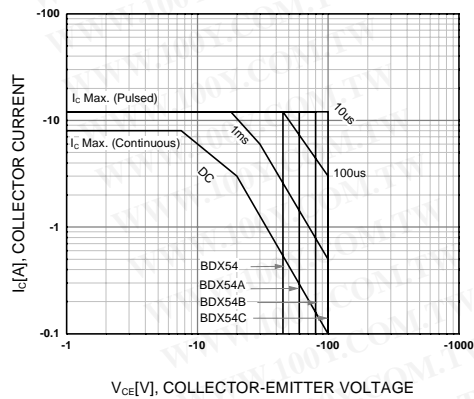


Figure 5. Safe Operating Area

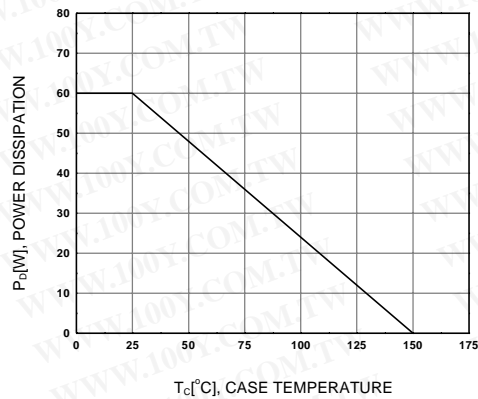


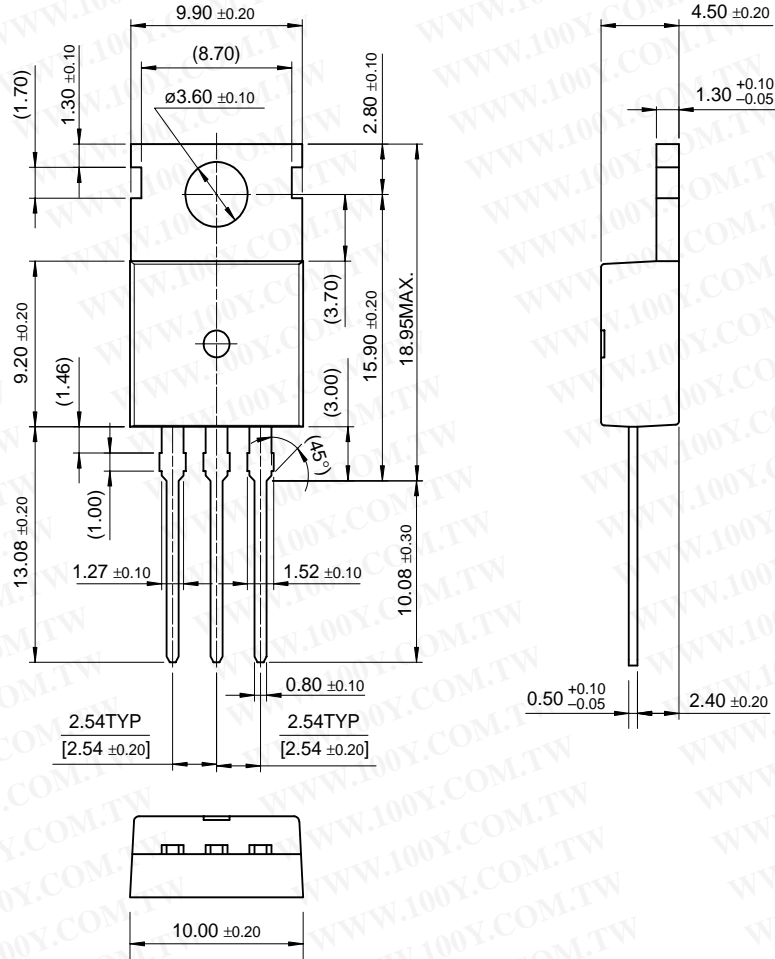
Figure 6. Power Derating

# Package Dimensions

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## TO-220



Dimensions in Millimeters

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POP™  
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QFET™  
QST™  
Quiet Series™  
SuperSOT™-3  
SuperSOT™-6

SuperSOT™-8  
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### Definition of Terms

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